



MCH6544

Bipolar Transistor 50V, 0.5A, Low VCE(sat) NPN Single MCPH6

ON Semiconductor®

<http://onsemi.com>

Applications

- Relay drivers, lamp drivers, motor drivers

Features

- Composite type with an NPN transistor contained in one package facilitating high-density mounting
- Ultrasmall package facilitates miniaturization in end products

Specifications

Absolute Maximum Ratings at Ta=25°C

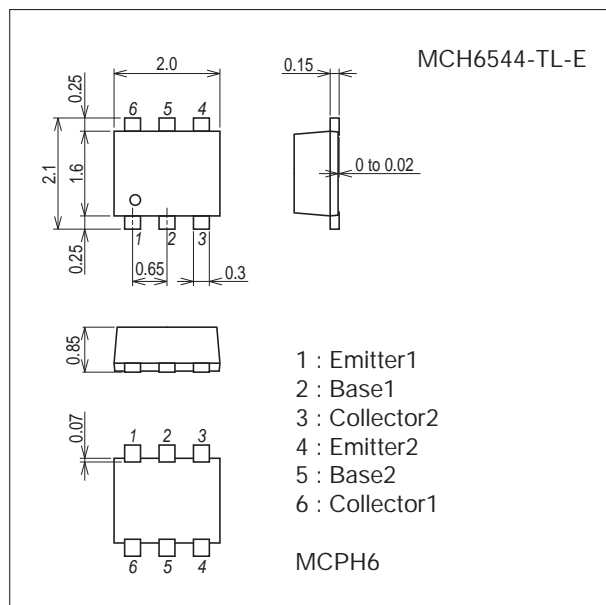
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CB0}		60	V
Collector-to-Emitter Voltage	V _{CEO}		50	V
Emitter-to-Base Voltage	V _{EB0}		5	V
Collector Current	I _C		500	mA
Collector Current (Pulse)	I _{CP}		1.5	A
Collector Dissipation	P _C	When mounted on ceramic substrate (600mm ² ×0.8mm) 1unit	0.5	W
Total Power Dissipation	P _T	When mounted on ceramic substrate (600mm ² ×0.8mm)	0.55	W
Junction Temperature	T _J		150	°C
Storage Temperature	T _{stg}		-55 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

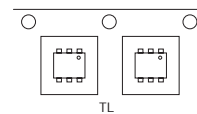
7022A-011



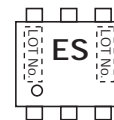
Product & Package Information

- Package : MCPH6
- JEITA, JEDEC : SC-88, SC-70-6, SOT-363
- Minimum Packing Quantity : 3,000 pcs./reel

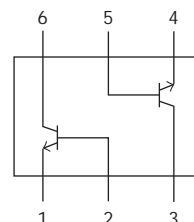
Packing Type : TL



Marking



Electrical Connection

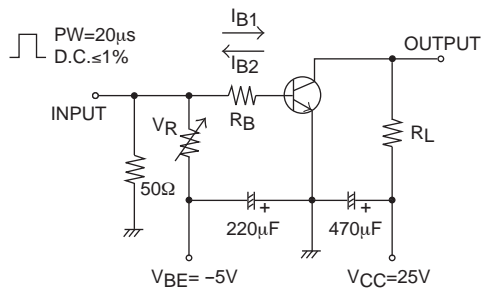


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Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=40V, I_E=0A$			100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB}=4V, I_C=0A$			100	nA
DC Current Gain	h_{FE}	$V_{CE}=2V, I_C=10mA$	300		800	
Gain-Bandwidth Product	f_T	$V_{CE}=10V, I_C=50mA$		500		MHz
Output Capacitance	C_{ob}	$V_{CB}=10V, f=1MHz$		2.8		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA, I_B=10mA$		50	100	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=100mA, I_B=10mA$		0.9	1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=10\mu A, I_E=0A$	60			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=1mA, R_{BE}=\infty$	50			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=10\mu A, I_C=0A$	5			V
Turn-ON Time	t_{on}	See specified Test Circuit.		30		ns
Storage Time	t_{stg}			340		ns
Fall Time	t_f			55		ns

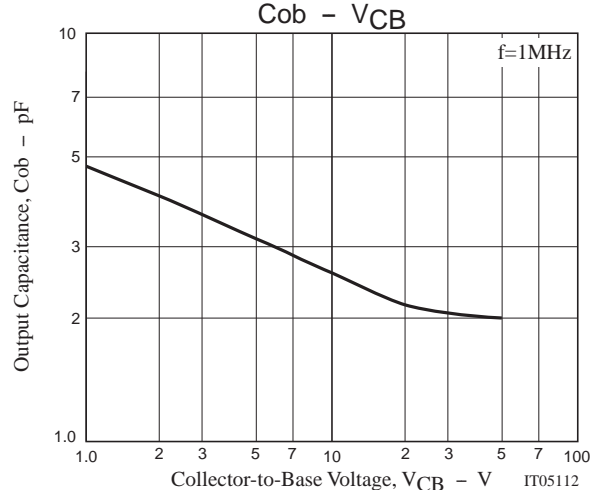
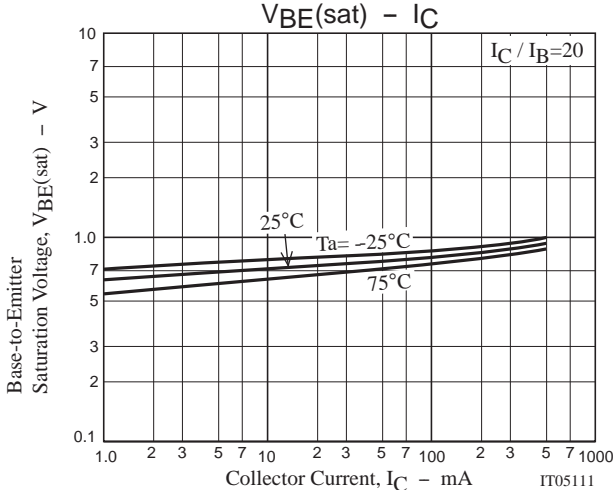
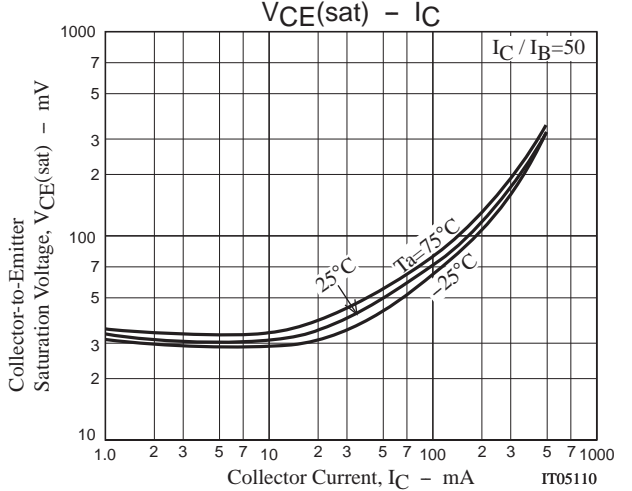
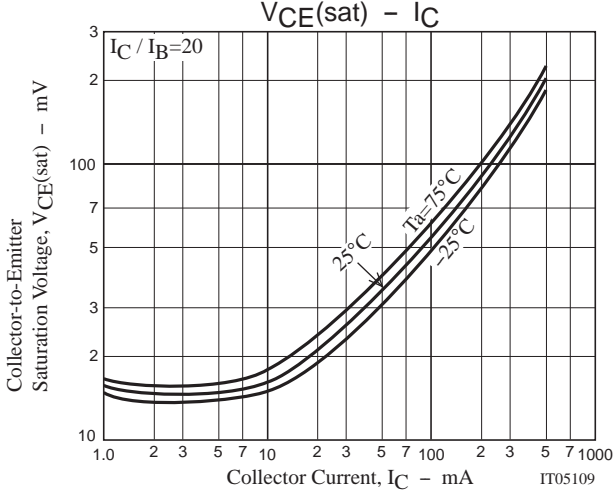
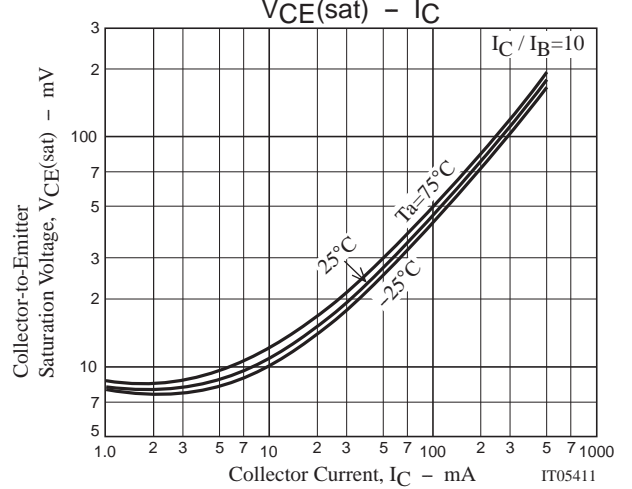
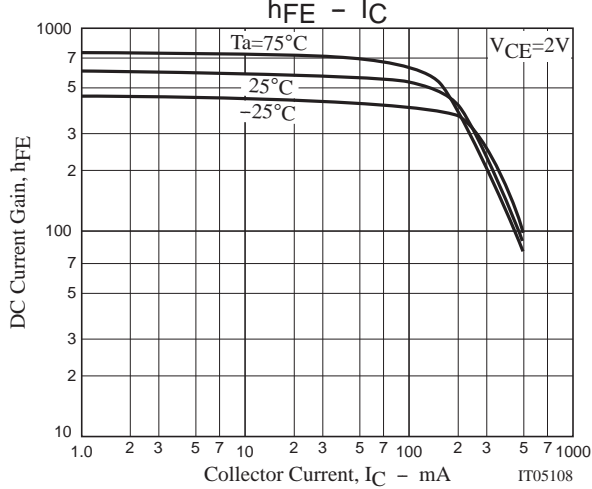
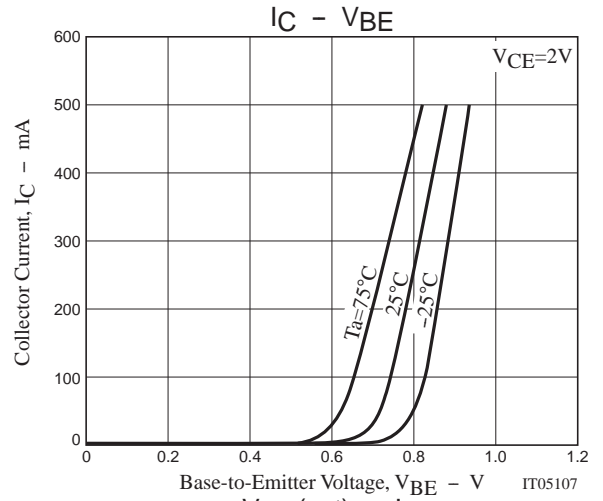
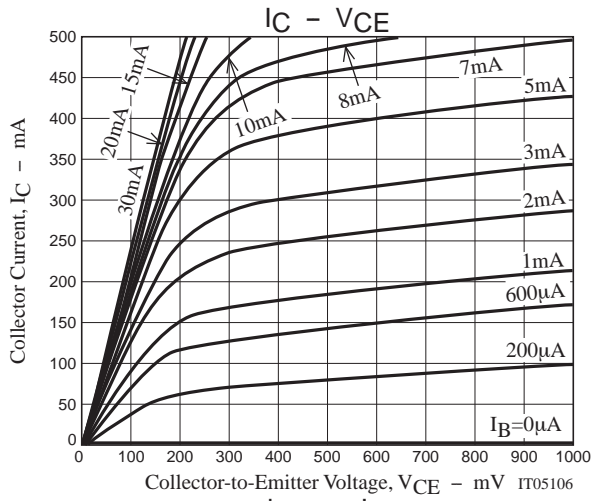
Switching Time Test Circuit



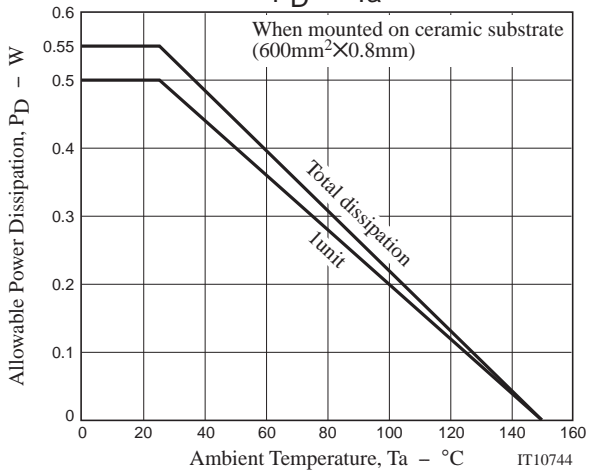
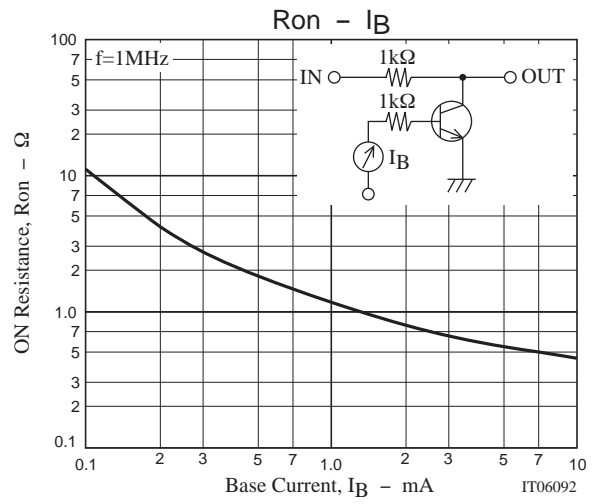
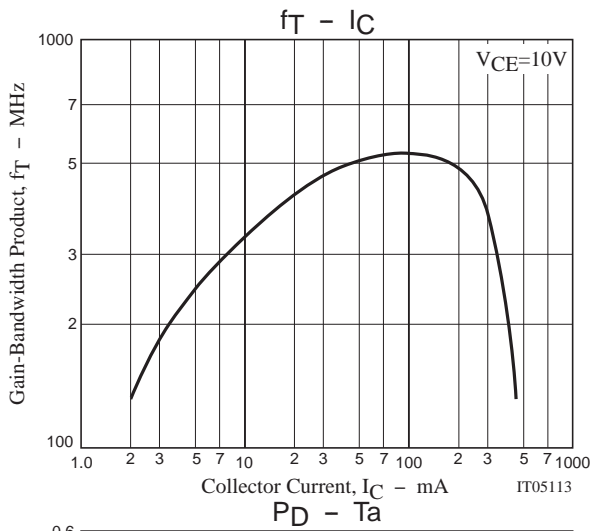
$$I_C = 20I_{B1} = -20I_{B2} = 200mA$$

Ordering Information

Device	Package	Shipping	memo
MCH6544-TL-E	MCPH6	3,000pcs./reel	Pb Free



MCH6544



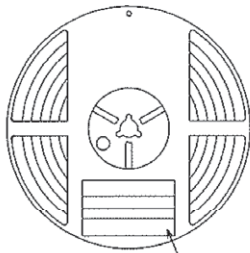
Embossed Taping Specification

MCH6544-TL-E

1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
MCPH6	MCP4	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

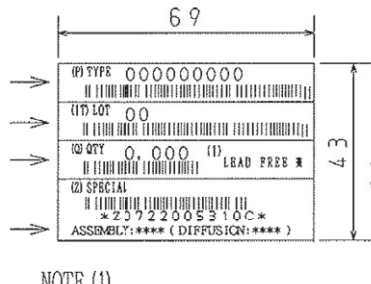
Packing method



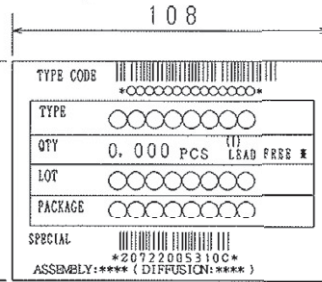
Type No.
LOT No.
Quantity
Origin

Reel label

Reel label, Inner box label
(unit :mm)



Outer box label
It is a label at the time of factory shipments.
The form of a label may change in physical distribution process.



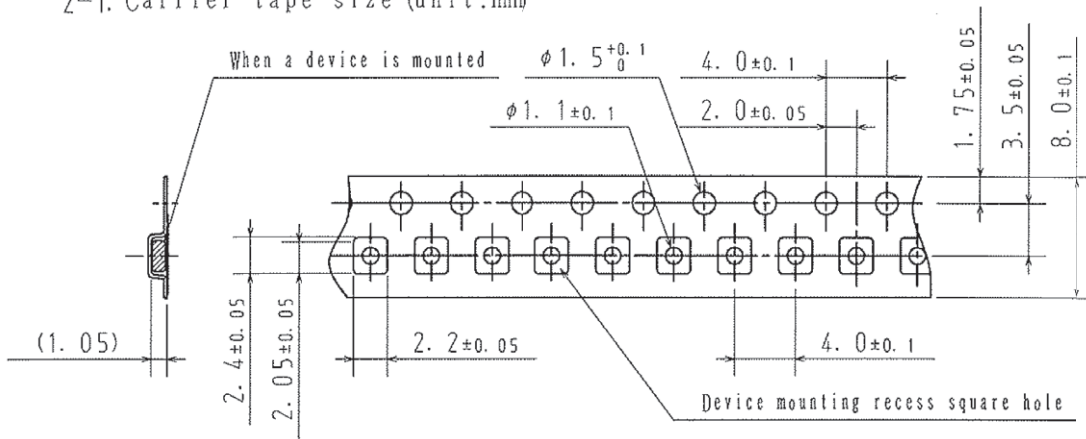
NOTE (1)

The LEAD FREE * description shows that the surface treatment of the terminal is lead free.

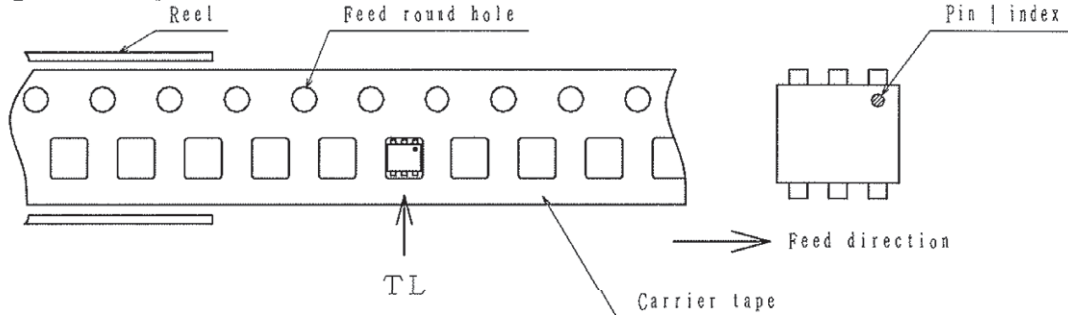
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

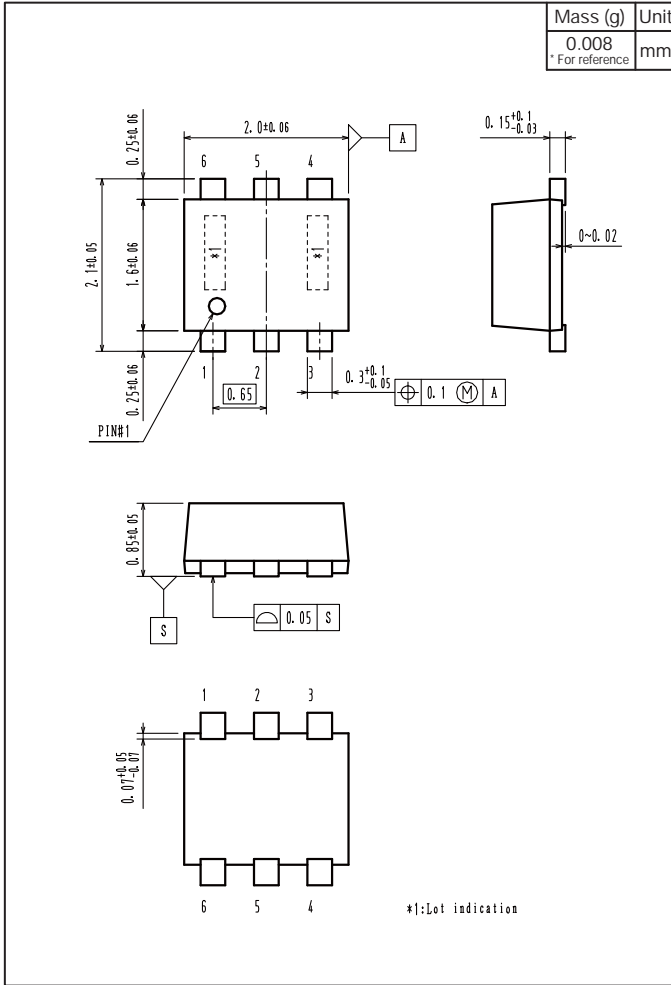


Those with pin | index on the feed hole side.....TL

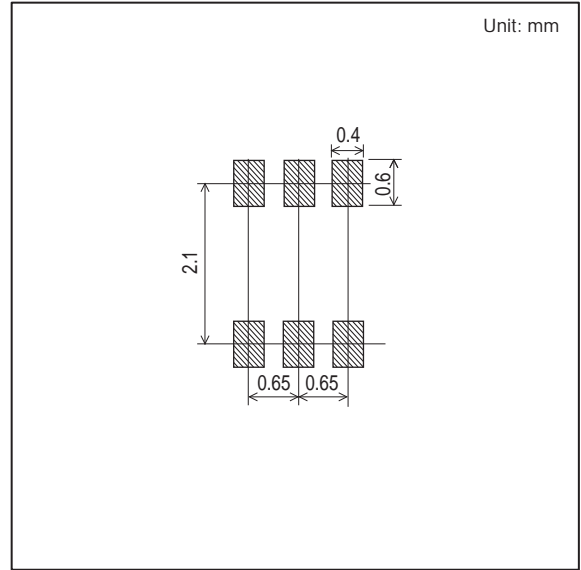
MCH6544

Outline Drawing

MCH6544-TL-E



Land Pattern Example



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